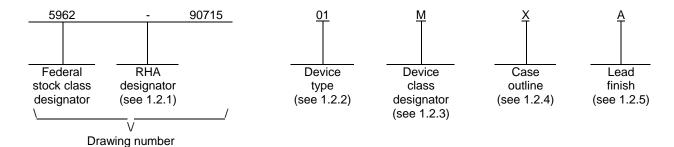
								R	EVISI	ONS										
LTR					D	ESCR	RIPTIO						DA	TE (YF	R-MO-	DA)		APPR	OVED	)
А		wing up		d to ref	lect cu	urrent	require	ements	s. Edit	orial cl	nange	S	01-02-12			Raymond Monnin				
В				te and	part o	of five y	/ear re	view.	tcr					07-0	1-31		Jo	seph I	Roden	beck
THE ORIGIN	IAL FIR	ST PA	GE O	F THIS	S DRA	AWING	S HAS	BEEN	REPL	ACED					Γ			Τ	Τ	
REV	AL FIR	ST PA	GE O	F THIS	S DRA	AWING	S HAS	BEEN	REPL	ACED										
REV SHEET																				
REV SHEET REV	В	В	В	В	В	В	В	В	В	В										
REV SHEET REV SHEET	B 15			B 18	B 19		B 21	B 22	B 23	B 24		Ω	R	R	R	R	R	R	R	R
REV SHEET REV SHEET REV STATU	B 15	В	В	B 18 RE\	B 19	В	B 21 B	B 22 B	B 23 B	B 24 B	В	B 6	B 7	В	В	B 10	B 11	B 12	B 13	B 14
REV SHEET REV SHEET	B 15	В	В	B 18 RE\	B 19 V EET	В	B 21 B 1	B 22 B 2	B 23	B 24	B 5	6	7	8	9	10	11	12	13	B 14
REV SHEET REV SHEET REV STATU OF SHEETS PMIC N/A STA	B 15	B 16	В	B 18 RE\ SHE PRE	B 19 V EET EPARE Ja	B 20	B 21 B 1	B 22 B 2	B 23 B	B 24 B	B 5	6 FEN	7 SE SI	8 JPPL BUS,	9 Y CE		11 COL 218-3	12 .UMB	13	
REV SHEET REV SHEET REV STATU OF SHEETS PMIC N/A STAMICR DR THIS D AVA FOR U	B 15	B 16 CUIT G NG IS E ALL	В	B 18 RE\ SHE PRE	B 19 V EET EPARE Ja ECKEE Vm J.	B 20 ED BY ames E	B 21 B 1	B 22 B 2	B 23 B	B 24 B 4	B 5	6 CC	7 SE SI DLUM http  T, ME	JPPL BUS, :://ww	Y CE, OHIO	10 NTER 0 432	11 2 COL 218-39 a.mil	12 .UMB 990	13	
REV SHEET REV SHEET REV STATU OF SHEETS PMIC N/A STAMICR DR THIS D AVA FOR U	B 15 IS S ANDAR OCIRC AWIN AILABL ISE BY RTMEN NCIES	B 16 CUIT G NG IS E ALL NTS OF TH	B 17	B 18 REV SHE PRE	B 19 V EET PARE Ja ECKEE Vm J.	B 20 ED BY ames E D BY Johnse	B 21 B 1	B 22 B 2	B 23 B 3	B 24 B 4	B 5	6 CC	7 SE SI DLUM http  T, ME	JPPL BUS, :://ww	Y CE, OHIO	NTER D 432 CC.dla	11 2 COL 218-39 a.mil	12 .UMB 990	13	

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#### 1. SCOPE

- 1.1 <u>Scope</u>. This drawing documents two product assurance class levels consisting of high reliability (device classes Q and M) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels are reflected in the PIN.
  - 1.2 PIN. The PIN is as shown in the following example:



- 1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. Device class M RHA marked devices meet the MIL-PRF-38535, appendix A specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.
  - 1.2.2 Device type(s). The device type(s) identify the circuit function as follows:

Device type	Generic number	Circuit function	Access time
01	7204S120	4K X 9 FIFO	120 ns
02	7204S80	4K X 9 FIFO	80 ns
03	7C432-65, 7204S65	4K X 9 FIFO	65 ns
04	7C432-50, 7204S50	4K X 9 FIFO	50 ns
05	7C433-40, 7204S40	4K X 9 FIFO	40 ns
06	7C433-30, 7204A-30	4K X 9 FIFO	30 ns
07	7204A-20	4K X 9 FIFO	20 ns

1.2.3 <u>Device class designator</u>. The device class designator is a single letter identifying the product assurance level as follows:

Device class

Device requirements documentation

M

Vendor self-certification to the requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535, appendix A

Q or V

Certification and qualification to MIL-PRF-38535

1.2.4 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
U	CDIP3-T28 or GDIP4-T28	28	Dual-in-line
Χ	GDIP1-T28 or CDIP2-T28	28	Dual-in-line
Υ	GDFP2-F28	28	Flat pack
Z	CQCC1-N32	32	Rectangular leadless chip carrier

1.2.5 <u>Lead finish</u>. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

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#### 1.3 Absolute maximum ratings. 1/

#### 1.4 Recommended operating conditions.

#### 2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbooks</u>. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

#### DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

#### DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.

MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

#### DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings.

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at <a href="http://assist.daps.dla.mil/quicksearch/">http://assist.daps.dla.mil/quicksearch/</a> or <a href="http://assist.daps.dla.mil/quicksearch/">http:

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Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

<sup>2/</sup> V<sub>IH</sub> is 2.2 V minimum for all input pins except XI which is 3.5 V minimum.

2.2 <u>Non-Government publications</u>. The following documents form a part of this document to the extent specified herein. Unless otherwise specified, the issues of the documents are the issues of the documents cited in the solicitation.

#### ELECTRONICS INDUSTRIES ALLIANCE (EIA)

JEDEC Standard EIA/JESD 78 - IC Latch-Up Test.

(Applications for copies should be addressed to the Electronics Industries Alliance, 2500 Wilson Boulevard, Arlington, VA 22201; <a href="http://www.jedec.org">http://www.jedec.org</a>.)

(Non-Government standards and other publications are normally available from the organizations that prepare or distribute the documents. These documents also may be available in or through libraries or other informational services.)

2.3 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

#### 3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.
  - 3.2.1 <u>Case outlines</u>. The case outlines shall be in accordance with 1.2.4 herein.
  - 3.2.2 Terminal connections. The terminal connections shall be as specified on figure 1.
  - 3.2.3 <u>Truth tables</u>. The truth tables shall be as specified on figure 2.
- 3.2.4 <u>Die overcoat</u>. Polyimide and silicone coatings are allowable as an overcoat on the die for alpha particle protection only. Each coated microcircuit inspection lot (see inspection lot as defined in MIL-PRF-38535) shall be subjected to and pass the internal moisture content test at 5000 ppm (see method 1018 of MIL-STD-883). The frequency of the internal water vapor testing shall not be decreased unless approved by the preparing activity. Samples may be pulled anytime after seal.
- 3.3 <u>Electrical performance characteristics and postirradiation parameter limits</u>. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.
- 3.5 <u>Marking</u>. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.
- 3.5.1 <u>Certification/compliance mark</u>. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.

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- 3.6 <u>Certificate of compliance</u>. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DSCC-VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.
- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 <u>Notification of change for device class M</u>. For device class M, notification to DSCC-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change that affects this drawing.
- 3.9 <u>Verification and review for device class M.</u> For device class M, DSCC, DSCC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
- 3.10 <u>Microcircuit group assignment for device class M</u>. Device class M devices covered by this drawing shall be in microcircuit group number 105 (see MIL-PRF-38535, appendix A).

#### 4. VERIFICATION

- 4.1 <u>Sampling and inspection</u>. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.
- 4.2 <u>Screening</u>. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.
  - 4.2.1 Additional criteria for device class M.
    - a. Burn-in test, method 1015 of MIL-STD-883.
      - (1) Test condition C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015.
      - (2)  $T_A = +125^{\circ}C$ , minimum.
    - b. Interim and final electrical test parameters shall be as specified in table II herein.
  - 4.2.2 Additional criteria for device classes Q and V.
    - a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
    - b. Interim and final electrical test parameters shall be as specified in table II herein.
    - Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.

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TABLE I. Electrical performance characteristics.

		Conditions $\frac{1}{2}$ -55°C $\leq$ T <sub>C</sub> $\leq$ +125°C					
Test	Symbol	$4.5 \text{ V} \le \text{V}_{CC} \le 5.5 \text{ V}$	Group A subgroups	Device type	Lir	nits	Unit
		unless otherwise specified			Min	Max	
Output high voltage	V <sub>OH</sub>	$V_{CC} = 4.5 \text{ V}, I_{OH} = -2.0 \text{ mA}$ $V_{IN} = V_{IH}, V_{IL}$	1, 2, 3	All	2.4		V
Output low voltage	V <sub>OL</sub>	$V_{CC}$ = 4.5 V, $I_{OL}$ = 8.0 mA $V_{IN}$ = $V_{IH}$ , $V_{IL}$	1, 2, 3	All		0.4	V
Input high voltage	V <sub>IH</sub> <u>2</u> / <u>3</u> /		1, 2, 3	All	2.2		V
Input low voltage	V <sub>IL</sub>		1, 2, 3	All		0.8	V
Input leakage current	I <sub>IX</sub>	V <sub>IN</sub> = 5.5 V to GND	1, 2, 3	All	-10	10	μА
Output leakage current	I <sub>OZ</sub>	$V_{CC} = 5.5 \text{ V},$ $\overline{R} = V_{IH}, V_{OUT} = 5.5 \text{ V} \text{ and GND}$	1, 2, 3	All	-10	10	μΑ
Operating supply current	I <sub>CC1</sub>	$V_{CC} = 5.5 \text{ V}, I_{OUT} = 0 \text{ mA}$ $f = 1/t_{RC}$ $\overline{W}, \overline{R}, D_O - D_8 \text{ pins are}$	1, 2, 3	01-05		150	mA
		toggling between 0 V and 3 V $\overline{FF}$ , $\overline{XO}/\overline{HF}$ = 0 mA		06		155	
		$\begin{array}{c} Q_0 - Q_8 = 0 \text{ mA} \\ \overline{MR}, \overline{FL}/\overline{RT} = 3.0 \text{ V} \end{array}$		07		200	
Standby current	I <sub>CC2</sub>	$V_{CC} = 5.5 \text{ V}, I_{OUT} = 0 \text{ mA}$ All inputs = $V_{IH}$ $\overline{FF}$ , $\overline{XO}/\overline{HF} = 0 \text{ mA}$ $Q_0 - Q_8 = 0 \text{ mA}$	1, 2, 3	All		30	mA
Power down current	I <sub>CC3</sub>	$V_{CC} = 5.5 \text{ V}, I_{OUT} = 0 \text{ mA}$ All inputs = $V_{CC}$ -0.2 V $\overline{FF}$ , $\overline{XO}/\overline{HF}$ = 0 mA $Q_0 - Q_8 = 0 \text{ mA}$	1, 2, 3	All		25	mA
Input capacitance	C <sub>IN</sub> <u>4</u> /	$V_{CC} = 5.0 \text{ V}, V_{IN} = 0 \text{ V}$ $T_A = +25^{\circ}\text{C}, f = 1 \text{ MHz}$ See 4.4.1e	4	All		8	pF
Output capacitance	C <sub>OUT</sub> <u>4</u> /	$V_{CC} = 5.0 \text{ V}, V_{OUT} = 0 \text{ V}$ $T_A = +25^{\circ}\text{C}, f = 1 \text{ MHz}$ See 4.4.1e	4	All		12	pF
Functional tests		See 4.4.1c	7, 8	All			

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TAE	BLE I. Electrical performance chara	acteristics - co	ntinued.			
Symbol	Conditions $\underline{1}/$ -55°C $\leq$ T <sub>C</sub> $\leq$ +125°C 4.5 V $\leq$ V <sub>CC</sub> $\leq$ 5.5 V	Group A subgroups	Device type	Lim	nits	Unit
	unless otherwise specified			Min	Max	
t <sub>RC</sub>	See figure 3	9, 10, 11	01	140		ns
			02	100		
			03	80		
			04	65		
			05	50		
			06	40		
			07	30		
t <sub>A</sub>		9, 10, 11	01		120	ns
			02		80	
			03		65	
			04		50	
			05		40	
			06		30	
			07		20	
t <sub>RR</sub>		9, 10, 11	01, 02	20		ns
			03, 04	15		
			05-07	10		
t <sub>LZR</sub>		9, 10, 11	All	3		ns
t <sub>DVR</sub>		9, 10, 11	All	3		ns

9, 10, 11

9, 10, 11

9, 10, 11

9, 10, 11

02-04

ns

ns

ns

ns

See footnotes at end of table.

Test

Read cycle time

Access time

Read recovery time

Read low to low-Z

4/, 5/

Read high to data valid

Read high to high-Z

Read pulse width

Write cycle time

Write pulse width

<u>6</u>/

<u>4</u>/, <u>5</u>/

<u>6</u>/

 $t_{HZR}$ 

 $t_{\mathsf{PR}}$ 

 $t_{WC}$ 

 $t_{\text{PW}}$ 

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	I AL	BLE I. Electrical performance char	<u> </u>	minucu.			
Test	Symbol	Conditions $\frac{1}{}$ -55°C $\leq$ T <sub>C</sub> $\leq$ +125°C $4.5$ V $\leq$ V <sub>CC</sub> $\leq$ 5.5 V	Group A subgroups	Device type	Lin	nits	Unit
		unless otherwise specified			Min	Max	
Write high to low-Z <u>4</u> /, <u>5</u> /, <u>7</u> /	t <sub>HWZ</sub>	See figure 3	9, 10, 11	All	5		ns
Write recovery time	t <sub>WR</sub>		9, 10, 11	01, 02	20		ns
				03, 04	15		
				05-07	10		
Data setup time	etup time t <sub>SD</sub>		9, 10, 11	01, 02	40		ns
				03, 04	30		
				05	20		
				06	18		
				07	12		
Data hold time	t <sub>HD</sub>		9, 10, 11	01-03	10		ns
				04	5		
				05-07	0		
Master reset cycle time	t <sub>MRSC</sub>		9, 10, 11	01	140		
				02	100		ns
				03	80		
				04	65		
				05	50		
				06	40		
Mantan na ant muda a			0.40.44	07	30		
Master reset pulse	t <sub>PMR</sub>		9, 10, 11	01	120		ns
width				02	80		
				03 04	65		
G/				05	50 40		
<u>6</u> /				06	30		
				07	20		
Master reset recovery	t		9, 10, 11	01, 02	20		ns
time	t <sub>RMR</sub>		9, 10, 11	03, 04	15		113
unic				05-07	10		
Read high to master	t <sub>RPW</sub>		9, 10, 11	01	120		ns
reset high	RPW		3, 10, 11	02	80		113
1000t riigiri				03	65		
<u>8</u> /				04	50		
<u>=</u>				05	40		
				06	30		
				07	20		
Write high to master	t <sub>WPW</sub>		9, 10, 11	01	120		ns
reset high				02	80		
ŭ				03	65		
<u>8</u> /				04	50		
_				05	40		
	1		1				

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	TAE	BLE I. Electrical performance char	acteristics - co	ntinued.			
Test	Symbol	Conditions $1/$ -55°C $\leq$ T <sub>C</sub> $\leq$ +125°C $4.5 \text{ V} \leq$ V <sub>CC</sub> $\leq$ 5.5 V	Group A subgroups	Device type	Lin	Limits	
		unless otherwise specified			Min	Max	
Retransmit cycle time	t <sub>RTC</sub>	See figure 3	9, 10, 11	01	140		ns
				02	100		
				03	80		
				04	65		
				05	50		
				06	45		
				07	45		
Retransmit pulse width	t <sub>PRT</sub>		9, 10, 11	01	120		ns
				02	80		
<u>6</u> /				03	65		
				04	50		
				05	40		
				06	35		
				07	35		
Retransmit recovery	t <sub>RTR</sub>		9, 10, 11	01, 02	20		ns
time				03, 04	15		
				05-07	10		
Master reset to empty	t <sub>EFL</sub>		9, 10, 11	01		140	ns
flag low				02		100	
				03		80	
				04		65	
				05		50	
				06		40	
				07		30	
Master reset to half-	t <sub>HFH</sub>		9, 10, 11	01		140	ns
full flag high				02		100	
				03		80	
				04		65	
				05		50	
				06		40	
				07		30	
Master reset to full	t <sub>FFH</sub>		9, 10, 11	01		140	ns
flag high				02		100	
				03		80	
				04		65	
				05		50	
				06		40	
		1		07		30	
Read low to empty flag	t <sub>REF</sub>		9, 10, 11	01-03		60	ns
low				04		45	
				05		35	

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TABLE I.	Electrical performance	characteristics	-	continued.	

Test	Symbol	Conditions $\underline{1}/$ -55°C $\leq$ T <sub>C</sub> $\leq$ +125°C	Group A	Device	Lim	nits	Unit
		$4.5 \text{ V} \le \text{V}_{\text{CC}} \le 5.5 \text{ V}$ unless otherwise specified	subgroups	type	Min	Max	=
Read high to full flag	t <sub>RFF</sub>	See figure 3	9, 10, 11	01-03	IVIIII	60	ns
high	'RFF	Gee figure 3	3, 10, 11	04		45	113
9				05		35	1
				06		30	
				07		28	1
Write high to empty	t <sub>WEF</sub>		9, 10, 11	01-03		60	ns
flag high				04		45	
				05		35	
				06		30	
				07		28	
Write low to full flag	t <sub>WFF</sub>		9, 10, 11	01-03		60	ns
low				04		45	
				05		35	
				06 07		30 28	
Write low to half-full	•		9, 10, 11	01		140	no
flag low	t <sub>WHF</sub>		9, 10, 11	02		100	ns
liag low				03		80	-
				04		65	
				05		50	
				06		40	1
				07		30	
Read high to half-full	t <sub>RHF</sub>		9, 10, 11	01		140	ns
flag high				02		100	
				03		85	
				04		65	
				05		50	
				06		40	
				07		30	
Effective read pulse	t <sub>RPE</sub>		9, 10, 11	01	120		ns
width after empty				02	80		
flag high				03 04	65 50		
				05	40		
				06	30		1
				07	20		1
Effective write pulse	t <sub>WPF</sub>		9, 10, 11	01	120		ns
width after full	*****			02	80		1
flag high				03	65		1
				04	50		]
				05	40		
				06	30		
				07	20		

STANDARD	
MICROCIRCUIT DRAWING	

DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990

SIZE <b>A</b>		5962-90715
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#### TABLE I. <u>Electrical performance characteristics</u> - continued.

Test	Symbol	Conditions <u>1</u> / -55°C $\leq$ T <sub>C</sub> $\leq$ +125°C 4.5 V $\leq$ V <sub>CC</sub> $\leq$ 5.5 V	Group A subgroups	Device type	Lim	nits	Unit
		unless otherwise specified	00.0 g. 0 u.p 0	1,750	Min	Max	
Expansion out low	t <sub>XOL</sub>	See figure 3	9, 10, 11	01		120	ns
delay from clock				02		80	
				03		65	
				04		50	
<u>4</u> /				05		40	
				06		30	
				07		20	
Expansion out high	t <sub>XOH</sub>		9, 10, 11	01		120	ns
delay from clock				02		80	
				03		65	
				04		50	
<u>4</u> /				05		40	
				06		30	
				07		20	

- 1/ AC tests are performed with input rise and fall times of 5 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V, and the output load in figure 4, circuit A.
- 2/ These are absolute values with respect to device ground and all overshoots due to system or tester noise are included.
- $\underline{3}$ / V<sub>IH</sub> is 2.2 V minimum for all input pins except  $\overline{XI}$  which is 3.5 V minimum.
- 4/ Tested initially and after any design or process changes that affect that parameter, and therefore shall be guaranteed to the limits specified in table I.
- 5/ Transition is measured at steady state high level -500 mV or steady-state low level +500 mV on the output from the 1.5 V level on the input, with output load figure 4 circuit B.
- 6/ Pulse widths less than minimum are not allowed.
- 7/ Only applies to read data flow-through mode.
- 8/ Values guaranteed by design and not currently tested.

STANDARD
MICROCIRCUIT DRAWING

DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990

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Device types	All	
Case outlines	U, X, and Y	Z
Terminal number	Terminal	symbol
1	$\overline{W}$	NC
2	D <sub>8</sub>	$\overline{W}$
3	$D_3$	D <sub>8</sub>
4	$D_2$	$D_3$
5	D <sub>1</sub>	$D_2$
6	D <sub>0</sub>	$D_1$
7	XI	$D_0$
8	FF	$\overline{XI}$
9	$Q_0$	FF
10	$Q_1$	$Q_0$
11	$Q_2$	$Q_1$
12	$Q_3$	NC
13	$Q_8$	$Q_2$
14	GND	$Q_3$
15	R	Q <sub>8</sub>
16	$Q_4$	GND
17	$Q_5$	NC
18	$Q_6$	R
19	$Q_7$	$Q_4$
20	XO/HF	$Q_5$
21	EF	$Q_6$
22	MR	$Q_7$
23	FL/RT	XO/HF
24	D <sub>7</sub>	EF
25	$D_6$	MR
26	$D_5$	FL/RT
27	$D_4$	NC
28	V <sub>CC</sub>	$D_7$
29		$D_6$
30		$D_5$
31		$D_4$
32		$V_{CC}$

NC = no connection

FIGURE 1. Terminal connections.

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## Reset and retransmit Single device configuration/width expansion mode

Mode	Inputs		Internal status		Outputs			
	MR	RT	XI	Read pointer	Write pointer	EF	FF	HF
Reset	0	Х	0	Location zero	Location zero	0	1	1
Retransmit	1	0	0	Location zero	Unchanged	Χ	Х	Χ
Read/write	1	1	0	Increment 1/	Increment 1/	Χ	Х	X

<sup>1/</sup> Pointer will increment if flag is high.

#### Reset and first load truth table Depth expansion/compound expansion mode

	Inputs		Internal status		Outputs		
Mode	MR	FL	XI	Read pointer	Write pointer	EF	FF
Reset first device	0	0	<u>1</u> /	Location zero	Location zero	0	1
Reset all other devices	0	1	<u>1</u> /	Location zero	Location zero	0	1
Read/write	1	Х	<u>1</u> /	Χ	X	Х	Χ

 $<sup>\</sup>underline{1}$ /  $\overline{XI}$  is connected to  $\overline{XO}$  of previous device.

#### NOTE:

 $\overline{\text{MR}}$  = Reset input,  $\overline{\text{FL}}/\overline{\text{RT}}$  = First load/retransmit  $\overline{\text{EF}}$  = Empty flag output,  $\overline{\text{FF}}$  = Full flag output,  $\overline{\text{XI}}$  = Expansion input, and  $\overline{\text{HF}}$  = Half-full flag output 0 = Low level voltage 1 = High level voltage

X = Don't care

FIGURE 2. Truth tables.

# STANDARD MICROCIRCUIT DRAWING DEFENSE SUPPLY CENTER COLUMBUS COLUMBUS, OHIO 43218-3990 SIZE A SP62-90715 REVISION LEVEL B SHEET 13

#### ASYNCHRONOUS READ AND WRITE TIMING DIAGRAM

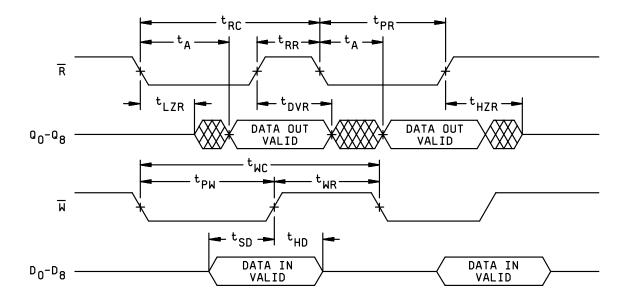
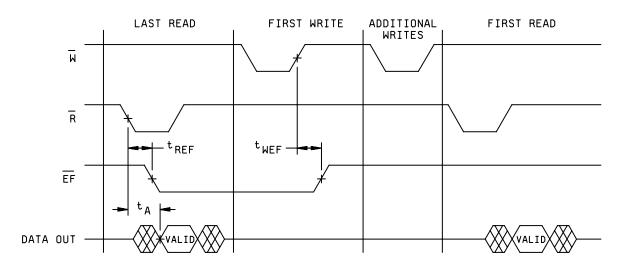


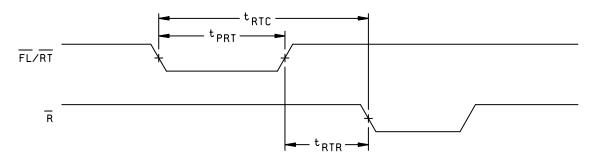
FIGURE 3. <u>Timing waveforms</u>.

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#### LAST READ TO FIRST WRITE EMPTY TIMING DIAGRAM



#### RETRANSMIT TIMING DIAGRAM



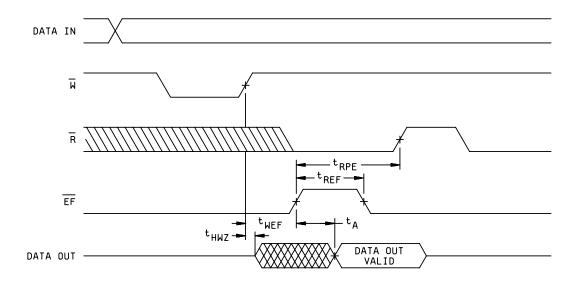
#### NOTES:

- 1.  $t_{RTC} = t_{RT} + t_{RTR}$
- 2. EF , HF , and FF may change state during retransmit as a result of the offset of the read and write pointers, but flags will be valid at t<sub>RTC</sub>.

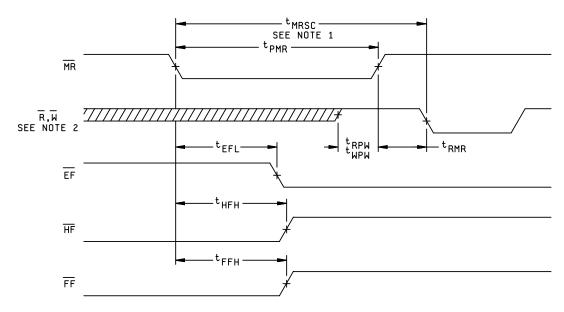
FIGURE 3. Timing waveforms - Continued.

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#### EMPTY FLAG AND READ BUBBLE-THROUGH MODE TIMING DIAGRAM



#### MASTER RESET TIMING DIAGRAM



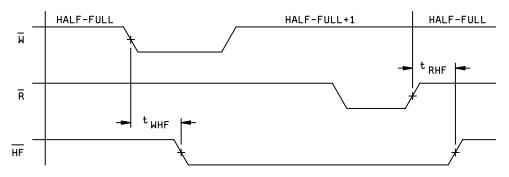
#### NOTES:

- 1.  $t_{MRSC} = t_{PMR} + t_{RMR}$ .
- 2.  $\overline{W}$  and  $\overline{R} = V_{IH}$  around the rising edge of  $\overline{MR}$ .

FIGURE 3. Timing waveforms - Continued.

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#### HALF-FULL FLAG TIMING DIAGRAM



#### LAST WRITE TO FIRST READ FULL FLAG TIMING DIAGRAM

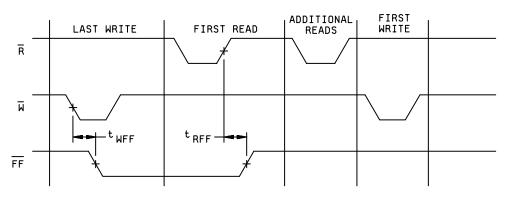


FIGURE 3. <u>Timing waveforms</u> – Continued.

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#### FULL FLAG AND WRITE BUBBLE-THROUGH MODE TIMING DIAGRAM

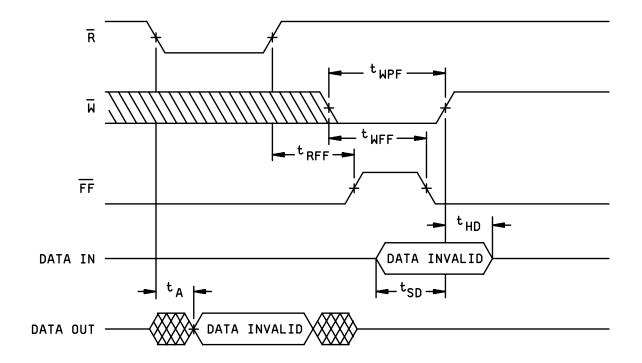
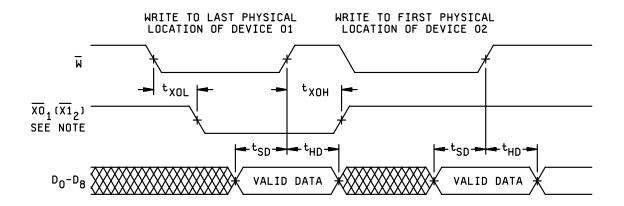
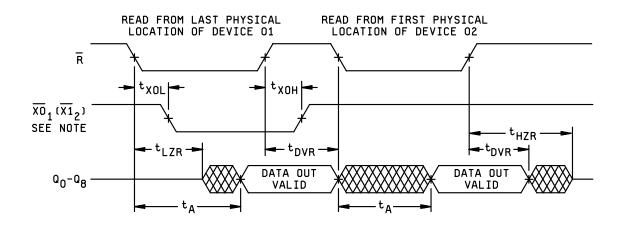


FIGURE 3. <u>Timing waveforms</u> – Continued.

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#### **EXPANSION TIMING DIAGRAM**

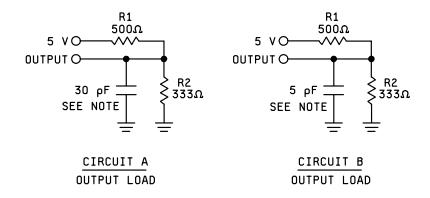




NOTE: Expansion out of device 1 (XO<sub>1</sub>) is connected to expansion in of device 2 ( $\overline{XI}_2$ ).

FIGURE 3. Timing waveforms - Continued.

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Note: Including scope and jig (minimum values).

AC test conditions

GND to 3.0 V
≤ 5 ns
1.5 V
1.5 V

FIGURE 4. Output load circuit and test conditions, or equivalent.

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- 4.3 <u>Qualification inspection for device classes Q and V</u>. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).
- 4.4 <u>Conformance inspection</u>. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified herein. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).
  - 4.4.1 Group A inspection.
    - a. Tests shall be as specified in table IIA herein.
    - b. Subgroups 5 and 6 of table I of method 5005 of MIL-STD-883 shall be omitted.
    - c. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the truth table. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device.
    - d. O/V (latch-up) tests shall be measured only for initial qualification and after any design or process changes which may affect the performance of the device. For device class M, procedures and circuits shall be maintained under document revision level control by the manufacturer and shall be made available to the preparing activity or acquiring activity upon request. For device classes Q and V, the procedures and circuits shall be under the control of the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the preparing activity or acquiring activity upon request. Testing shall be on all pins, on five devices with zero failures. Latch-up test shall be considered destructive. Information contained in JEDEC Standard EIA/JESD 78 may be used for reference.
    - e. Subgroup 4 (C<sub>IN</sub> and C<sub>OUT</sub> measurements) shall be measured only for initial qualification and after any process or design changes which may affect input or output capacitance. Capacitance shall be measured between the designated terminal and GND at a frequency of 1 MHz. Sample size is 15 devices with no failures, and all input and output terminals tested.
  - 4.4.2 Group C inspection. The group C inspection end-point electrical parameters shall be as specified in table IIA herein.
  - 4.4.2.1 Additional criteria for device class M. Steady-state life test conditions, method 1005 of MIL-STD-883:
    - a. Test condition C or D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
    - b.  $T_A = +125^{\circ}C$ , minimum.
    - c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

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TABLE IIA. Electrical test requirements. 1/, 2/, 3/, 4/, 5/

Line	Test	Subgroups	Subo	groups
No.	requirements	(in accordance with	(per MIL-F	PRF-38535,
		MIL-STD-883,	table III)	
		method 5005, table I)		
		Device class M	Device class Q	Device class V
1	Interim electrical parameters (see 4.2)			(1, 7, 9) or (2, 8A, 10)
2	Static burn-in I method 1015	Not required	Not required	Required
3	Same as line 1			1*, 7* Δ
4	Dynamic burn-in (method 1015)	Required	Required	Required
5	Same as line 1			1* Δ
6	Final electrical parameters	1*, 2, 3, 7*, 8A, 8B, 9, 10, 11	1*, 2, 3, 7*, 8A, 8B, 9, 10, 11	1*, 2, 3, 7*, 8A, 8B, 9, 10, 11
7	Group A test requirements	1, 2, 3, 4**, 7, 8A, 8B, 9, 10, 11	1, 2, 3, 4**, 7, 8A, 8B, 9, 10, 11	1, 2, 3, 4**, 7, 8A, 8B, 9, 10, 11
8	Group C end-point electrical parameters	2, 3, 7, 8A, 8B	2, 3, 7, 8A, 8B	1, 2, 3, 7, 8A, 8B, 9, 10, 11 Δ
9	Group D end-point electrical parameters	2, 3, 7, 8A, 8B	2, 3, 7, 8A, 8B	2, 3, 7, 8A, 8B
10	Group E end-point electrical parameters	1, 7, 9	1, 7, 9	1, 7, 9

- 1/ Blank spaces indicate tests are not applicable.
  2/ Any or all subgroups may be combined when using high-speed testers.
  3/ \* indicates PDA applies to subgroup 1 and 7.
  4/ \*\* see 4.4.1e.
  5/ Δ indicates delta limit (see table IIB) shall be required where specified, and the delta values shall be computed with reference to the previous interim electrical parameters (line 1).

TABLE IIB. <u>Delta limits at +25°C</u>.

Test <u>1</u> /	Device types		
	All		
$I_{IX}$	±10 percent of specified		
	value in table I		
$I_{OZ}$	±10 percent of specified		
	value in table I		
I <sub>CC2</sub>	±10 percent of specified		
	value in table I		

<sup>1/</sup> The above parameter shall be recorded before and after the required burn-in and life tests to determine the delta.

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- 4.4.2.2 Additional criteria for device classes Q and V. The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883
  - 4.4.3 Group D inspection. The group D inspection end-point electrical parameters shall be as specified in table II herein.
- 4.4.4 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein).
  - a. End-point electrical parameters shall be as specified in table II herein.
  - b. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535 for the RHA level being tested. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535, appendix A for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at T<sub>A</sub> = +25°C, after exposure, to the subgroups specified in table II herein.
- 4.5 <u>Delta measurements for device class V.</u> Delta measurements, as specified in table IIA, shall be made and recorded before and after the required burn-in screens and steady-state life tests to determine delta compliance. The electrical parameters to be measured, with associated delta limits are listed in table IIB. The device manufacturer may, at his option, either perform delta measurements or within 24 hours after burn-in perform final electrical parameter tests, subgroups 1, 7, and 9.

#### 5. PACKAGING

- 5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.
  - 6. NOTES
- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.1.1 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor prepared specification or drawing.
  - 6.1.2 Substitutability. Device class Q devices will replace device class M devices.
- 6.2 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692. Engineering Change Proposal.
- 6.3 <u>Record of users</u>. Military and industrial users should inform Defense Supply Center Columbus (DSCC) when a system application requires configuration control and which SMD's are applicable to that system. DSCC will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DSCC-VA, telephone (614) 692-0544.
- 6.4 <u>Comments</u>. Comments on this drawing should be directed to DSCC-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0547.

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6.5 Abbreviations, symbols, and definitions.	The abbreviations, symbols	, and definitions used herein are defined in
MIL-PRF-38535 and MIL-HDBK-1331.		

 $C_{\text{OUT}}$  ......Output and bidirectional output terminal capacitance.

GND.....Ground zero voltage potential.

 $\begin{array}{lll} I_{CC} & & Supply current. \\ I_{IX} & & Input current. \\ I_{OZ} & & Output current. \\ T_{C} & & Case temperature. \\ V_{CG} & & Positive supply voltage. \\ \end{array}$ 

#### 6.5.1 Waveforms.

Waveform symbol	Input	Output
	MUST BE VALID	WILL BE VALID
	CHANGE FROM H TO L	WILL CHANGE FROM H TO L
	CHANGE FROM L TO H	WILL CHANGE FROM L TO H
	DON'T CARE ANY CHANGE PERMITTED	CHANGING STATE UNKNOWN
		HIGH IMPEDANCE

#### 6.6 Sources of supply.

- 6.6.1 <u>Sources of supply for device classes Q and V</u>. Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DSCC-VA and have agreed to this drawing.
- 6.6.2 <u>Approved sources of supply for device class M.</u> Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DSCC-VA.

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#### STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 07-01-31

Approved sources of supply for SMD 5962-90715 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DSCC-VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DSCC maintains an online database of all current sources of supply at http://www.dscc.dla.mil/Programs/Smcr/.

Standard	Vendor	Vendor
microcircuit drawing	CAGE	similar
PIN <u>1</u> /	number	PIN <u>2</u> /
5962-9071501MXA	0C7V7	CY7C432-120DMB
	<u>3</u> /	IDT7204S120DB
5962-9071501MYA	0C7V7	CY7C433-120KMB
	<u>3</u> /	IDT7204S120XEB
5962-9071501MZA	0C7V7	CY7C433-120LMB
	<u>3</u> /	IDT7204S120LB
5962-9071501MUA	0C7V7	CY7C433-120DMB
	<u>3</u> /	IDT7204S120DB
5962-9071502MXA	0C7V7	CY7C432-80DMB
	<u>3</u> /	IDT7204S80DB
5962-9071502MYA	0C7V7	CY7C433-80KMB
	<u>3</u> /	IDT7204S80XEB
5962-9071502MZA	0C7V7	CY7C433-80LMB
	<u>3</u> /	IDT7204S80LB
5962-9071502MUA	0C7V7	CY7C433-80DMB
	<u>3</u> /	IDT7204S80DB
5962-9071503MXA	0C7V7	CY7C432-65DMB
	<u>3</u> /	IDT7204S65DB
5962-9071503MYA	0C7V7	CY7C433-65KMB
	<u>3</u> /	IDT7204S65XEB
5962-9071503MZA	0C7V7	CY7C433-65LMB
	<u>3</u> /	IDT7204S65LB
5962-9071503MUA	0C7V7	CY7C433-65DMB
	<u>3</u> /	IDT7204S65DB
5962-9071504MXA	0C7V7	CY7C432-50DMB
	<u>3</u> /	IDT7204S50DB
	<u>3</u> /	AM7204A-50BXA
5962-9071504MYA	0C7V7	CY7C433-50KMB
	<u>3</u> /	IDT7204S50DB
5962-9071504MZA	0C7V7	CY7C433-50LMB
	<u>3</u> /	IDT7204S50XEB
	<u>3</u> /	AM7204A-50BUA
5962-9071504MUA	0C7V7	CY7C433-50DMB
	<u>3</u> /	IDT7204S50DB

*		
Standard	Vendor	Vendor
microcircuit drawing	CAGE	similar
PIN <u>1</u> /	number	PIN <u>2</u> /
5962-9071505MXA	0C7V7	CY7C432-40DMB
	<u>3</u> /	IDT7204S40DB
5962-9071505MYA	0C7V7	CY7C433-40KMB
	<u>3</u> /	IDT7204S40XEB
5962-9071505MZA	0C7V7	CY7C433-40LMB
	<u>3</u> /	IDT7204S40LB
5962-9071505MUA	0C7V7	CY7C433-40DMB
	<u>3</u> /	IDT7204S40DB
5962-9071506MXA	0C7V7	CY7C432-30DMB
	<u>3</u> /	AM7204A-30BXA
5962-9071506MYA	0C7V7	CY7C433-30KMB
5962-9071506MZA	0C7V7	CY7C433-30LMB
	<u>3</u> /	AM7204A-30BUA
5962-9071506MUA	0C7V7	CY7C433-30DMB
5962-9071507MXA	0C7V7	CY7C432-20DMB
	<u>3</u> /	AM7204A-20/BXA
5962-9071507MYA	0C7V7	CY7C433-20KMB
5962-9071507MZA	0C7V7	CY7C433-20LMB
	<u>3</u> /	AM7204A-20/BUA
5962-9071507MUA	0C7V7	CY7C433-20DMB

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed contact the vendor to determine its availability.
- 2/ Caution. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- 3/ Not available from an approved source of supply.

Vendor CAGE number 0C7V7

Vendor name and address

QP Semiconductor 2945 Oakmead Village Ct. Santa Clara, CA 95051-0812

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